**Product data sheet** 

## 1. General description

P-channel enhancement mode MOSFET in an LFPAK56 (Power SO8) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

This product has been designed and qualified to AEC-Q101 standard for use in high-performance automotive applications such as reverse battery protection.

### 2. Features and benefits

- High thermal power dissipation capability
- Suitable for thermally demanding environments due to 175 °C rating
- Trench MOSFET technology
- AEC-Q101 qualified

## 3. Applications

- · Reverse battery protection
- Power management
- · High-side loadswitch
- Motor drive

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-40	V
$V_{GS}$	gate-source voltage		[1]	-20	-	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -10 V; T <sub>mb</sub> = 25 °C		-	-	-64	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C		-	-	110	W
Static characte	eristics						<u>'</u>
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = -10 V; $I_D$ = -10.8 A; $T_j$ = 25 °C		-	11	14	mΩ

[1]  $V_{GS} = -20 \text{ V/+}5 \text{ V}$  according AEC-Q101 at  $T_i = 175 \text{ °C}$ ;  $V_{GS} = -20 \text{ V/+}20 \text{ V}$  according AEC-Q101 at  $T_i = 150 \text{ °C}$ 



# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	mb	D
2	S	source		
3	S	source	a	G (F)
4	G	gate		s
mb	D	mounting base; connected to drain	LFPAK56; Power- SO8 (SOT669)	017aaa094

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package					
	Name	Description	Version			
BUK6Y14-40P	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669			

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
BUK6Y14-40P	6Y1440P

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-40	V
V <sub>GS</sub>	gate-source voltage		[1]	-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -10 V; T <sub>mb</sub> = 25 °C		-	-64	Α
		V <sub>GS</sub> = -10 V; T <sub>mb</sub> = 100 °C		-	-46	Α
I <sub>DM</sub>	peak drain current	single pulse; t <sub>p</sub> ≤ 10 µs; T <sub>mb</sub> = 25 °C		-	-257	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C		-	110	W
T <sub>j</sub>	junction temperature			-55	175	°C
T <sub>amb</sub>	ambient temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-65	175	°C
Source-drai	n diode			1	'	
Is	source current	T <sub>mb</sub> = 25 °C		-	-64	Α
I <sub>SM</sub>	peak source current	single pulse; t <sub>p</sub> ≤ 10 µs; T <sub>mb</sub> = 25 °C		-	-257	Α
ESD maxim	um rating			· · · · · · · · · · · · · · · · · · ·		
V <sub>ESD</sub>	electrostatic discharge voltage	НВМ	[2]	-	1000	V
Avalanche r	uggedness		'	'	'	
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	T <sub>j(init)</sub> = 25 °C; I <sub>D</sub> = -4.6 A; DUT in avalanche (unclamped)		-	94	mJ

- [1]  $V_{GS} = -20 \text{ V/+5 V}$  according AEC-Q101 at  $T_j = 175 \text{ °C}$ ;  $V_{GS} = -20 \text{ V/+20 V}$  according AEC-Q101 at  $T_j = 150 \text{ °C}$
- [2] Measured between all pins.

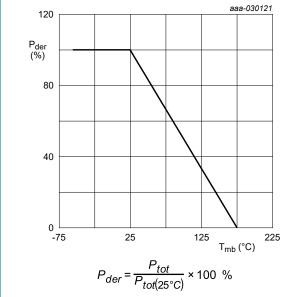


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

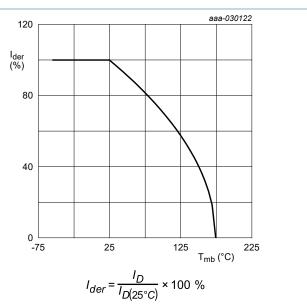


Fig. 2. Normalized continuous drain current as a function of mounting base temperature

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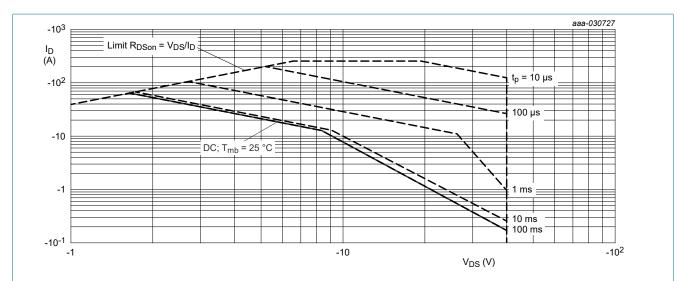
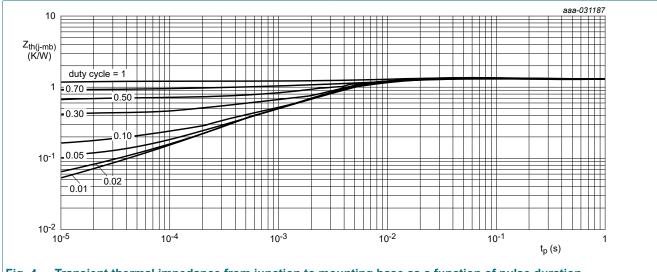


Fig. 3. Safe operating area; junction to mounting base; continuous and peak drain currents as a function of drain-source voltage

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base		-	1.1	1.4	K/W



40 V, P-channel Trench MOSFET

# 10. Characteristics

### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D = -250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	-40	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = -250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	-1.5	-2	-3	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = -40 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-1	μΑ
		V <sub>DS</sub> = -40 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 125 °C	-	-	-10	μΑ
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-100	nA
		V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	100	nA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = -10 V; I <sub>D</sub> = -10.8 A; T <sub>j</sub> = 25 °C	-	11	14	mΩ
	resistance	V <sub>GS</sub> = -10 V; I <sub>D</sub> = -10.8 A; T <sub>j</sub> = 175 °C	-	21	25	mΩ
		V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -8.1 A; T <sub>j</sub> = 25 °C	-	17	25	mΩ
g <sub>fs</sub>	forward transconductance	$V_{DS}$ = -10 V; $I_{D}$ = -4.8 A; $T_{j}$ = 25 °C	-	20	-	S
$R_G$	gate resistance	f = 1 MHz; T <sub>j</sub> = 25 °C	-	8.83	-	Ω
Dynamic ch	aracteristics					
Q <sub>G(tot)</sub>	total gate charge	V <sub>DS</sub> = -20 V; I <sub>D</sub> = -10.8 A; V <sub>GS</sub> = -10 V;	-	42.7	64	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	7.1	-	nC
Q <sub>GD</sub>	gate-drain charge		-	9.3	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = -20 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	2300	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	315	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	183	-	pF
d(on)	turn-on delay time	V <sub>DS</sub> = -20 V; I <sub>D</sub> = -10.8 A; V <sub>GS</sub> = -10 V;	-	10	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	30	-	ns
t <sub>d(off)</sub>	turn-off delay time	1	-	82	-	ns
t <sub>f</sub>	fall time		-	555	-	ns
Source-drai	in diode		•			
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -64.4 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-0.7	-1.2	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = -64.4 A; dI <sub>S</sub> /dt = 100 A/μs;	-	32	-	ns
Q <sub>r</sub>	recovered charge	V <sub>GS</sub> = -10 V; V <sub>DS</sub> = -20 V; T <sub>j</sub> = 25 °C	-	18	-	nC

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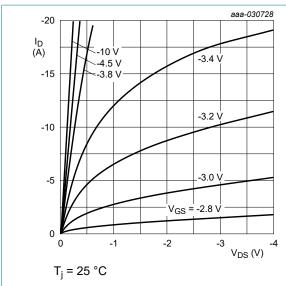


Fig. 5. Output characteristics: drain current as a function of drain-source voltage; typical values

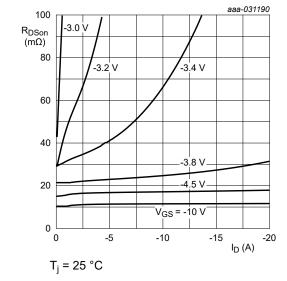


Fig. 7. Drain-source on-state resistance as a function of drain current; typical values

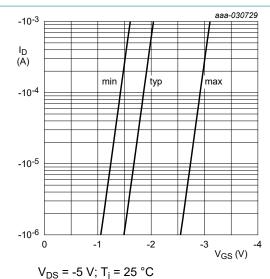


Fig. 6. Sub-threshold drain current as a function of

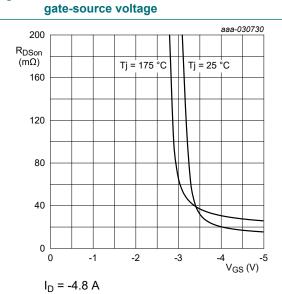


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

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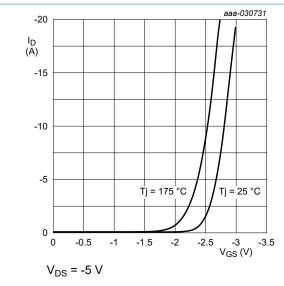


Fig. 9. Transfer characteristics: drain current as a function of gate-source voltage; typical values

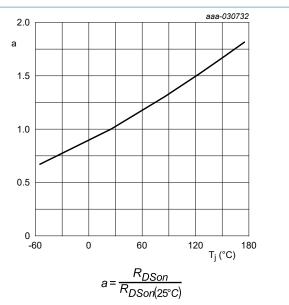


Fig. 10. Normalized drain-source on-state resistance as a function of junction temperature; typical values

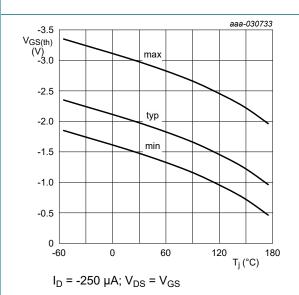


Fig. 11. Gate-source threshold voltage as a function of junction temperature

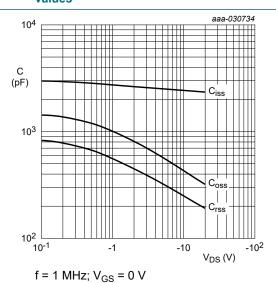


Fig. 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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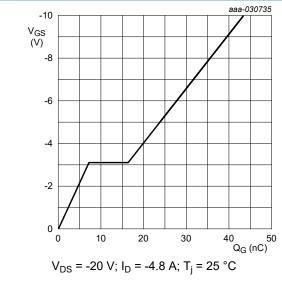


Fig. 13. Gate-source voltage as a function of gate charge; typical values

 $V_{GS} = 0 V$ 

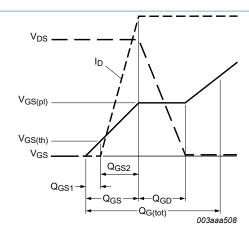


Fig. 14. Gate charge waveform definitions

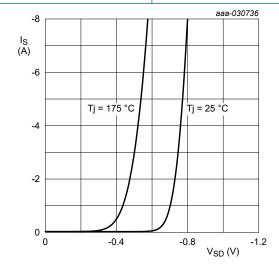
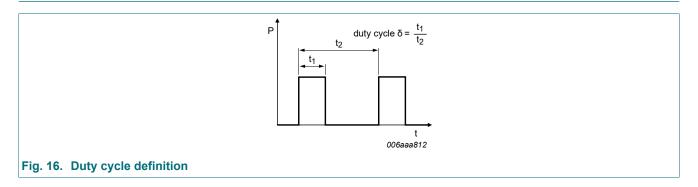


Fig. 15. Source current as a function of source-drain voltage; typical values

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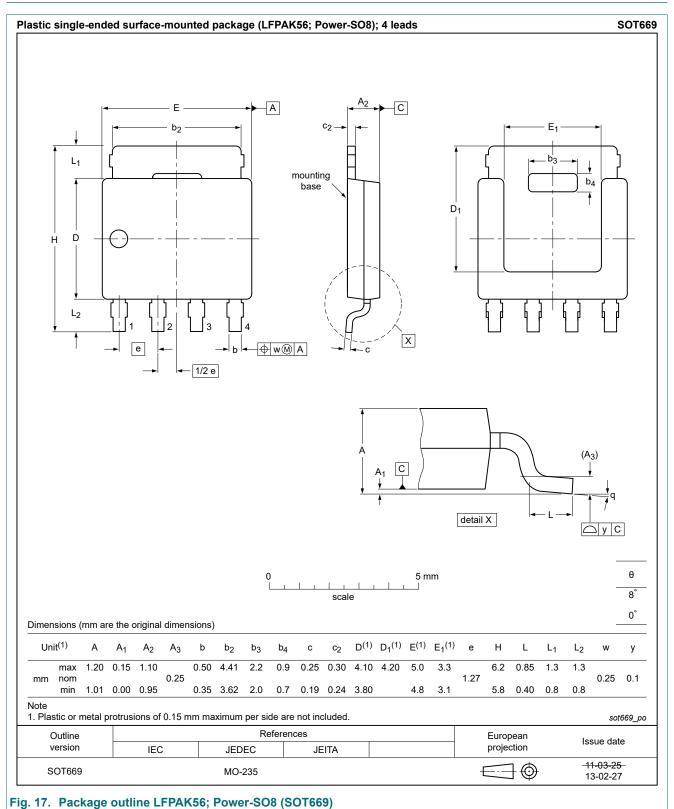
## 11. Test information



### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

# 12. Package outline



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40 V, P-channel Trench MOSFET

# 13. Revision history

### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BUK6Y14-40P v.1	20200316	Product data sheet	-	-

#### 40 V, P-channel Trench MOSFET

### 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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